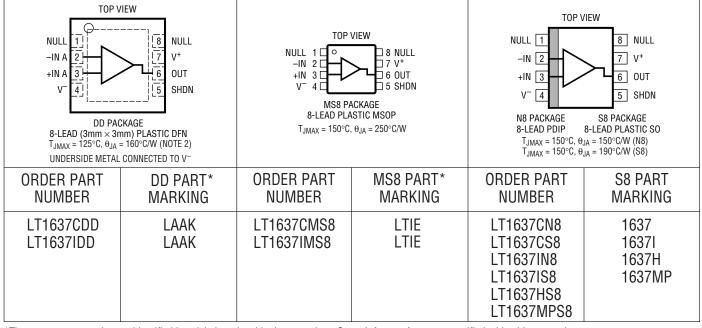
ABSOLUTE MAXIMUM RATINGS (Note 1)

Total Supply Voltage (V ⁺ to V ⁻) 44V
Input Differential Voltage 44V
Input Current ±25mA
Shutdown Pin Voltage Above V ⁻
Shutdown Pin Current ±10mA
Output Short-Circuit Duration (Note 2) Continuous
Operating Temperature Range (Note 3)
LT1637C/LT1637I –40°C to 85°C
LT1637H – 40°C to 125°C
LT1637MP55°C to 125°C

Specified Temperature Range (Note 4)
LT1637C/LT1637I –40°C to 85°C
LT1637H –40°C to 125°C
LT1637MP –55°C to 125°C
Junction Temperature 150°C
Junction Temperature (DD Package) 125°C
Storage Temperature Range –65°C to 150°C
Storage Temperature Range
(DD Package)65°C to 125°C
Lead Temperature (Soldering, 10 sec) 300°C

PACKAGE/ORDER INFORMATION



*The temperature grades are identified by a label on the shipping container. Consult factory for parts specified with wider operating temperature ranges.

3V AND 5V ELECTRICAL CHARACTERISTICS

The \bullet denotes the specifications which apply over the full operating temperature range of $-40^{\circ}C \le T_A \le 85^{\circ}C$, otherwise specifications are at $T_A = 25^{\circ}C$. $V_S = 3V$, 0V; $V_S = 5V$, 0V; $V_{SHDN} = V^-$, $V_{CM} = V_{OUT} =$ half supply unless otherwise specified. (Note 4)

				LT16	37C/LT16	371	
SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
V _{OS}	Input Offset Voltage	N8, S8 Packages $0^{\circ}C \leq T_{A} \leq 70^{\circ}C$ $-40^{\circ}C \leq T_{A} \leq 85^{\circ}C$	•		100	350 550 700	μV μV μV
			•		100	350 750 1100	μV μV μV
_		$ \begin{array}{l} \mbox{DD Package} \\ 0^\circ \mbox{C} \leq \mbox{T}_A \leq 70^\circ \mbox{C} \\ -40^\circ \mbox{C} \leq \mbox{T}_A \leq 85^\circ \mbox{C} \\ \end{array} $	•		125	550 950 1100	μV μV μV
		· · · · · · · · · · · · · · · · · · ·					1637fd



3V AND 5V ELECTRICAL CHARACTERISTICS

The \bullet denotes the specifications which apply over the full operating temperature range of $-40^{\circ}C \le T_A \le 85^{\circ}C$, otherwise specifications are at $T_A = 25^{\circ}C$. $V_S = 3V$, 0V; $V_S = 5V$, 0V; $V_{SHDN} = V^-$, $V_{CM} = V_{OUT} =$ half supply unless otherwise specified. (Note 4)

SYMBOL	_ PARAMETER CONDITIONS				LT1637C/LT1637 MIN TYP				
	Input Offset Voltage Drift (Note 9)	put Offset Voltage Drift (Note 9) N8, S8 Packages, $-40^{\circ}C \le T_A \le 85^{\circ}C$ MS8 Package, $-40^{\circ}C \le T_A \le 85^{\circ}C$		ge Drift (Note 9) N8, S8 Packages, $-40^{\circ}C \le T_A \le 85^{\circ}C$ MS8 Package, $-40^{\circ}C \le T_A \le 85^{\circ}C$			1 2	MAX 3 6	UNITS μV/°C μV/°C
		DDPackage, $-40^{\circ}C \le T_A \le 85^{\circ}C$	•		2	6	μV/°C		
l _{os}	Input Offset Current	V _{CM} = 44V (Note 5)			0.4	6.0 2.5	nA μA		
I _B	Input Bias Current	V _{CM} = 44V (Note 5) V _S = 0V	•		20 23 0.1	50 60	nA μA nA		
	Input Noise Voltage	0.1Hz to 10Hz			0.6		μV _{P-P}		
e _n	Input Noise Voltage Density	f = 1kHz			27		nV/√Hz		
i _n	Input Noise Current Density	f = 1kHz			0.08		pA/√Hz		
R _{IN}	Input Resistance	Differential Common Mode, V _{CM} = 0V to 44V		1 0.7	2.6 1.4		ΜΩ ΜΩ		
CIN	Input Capacitance				4		pF		
	Input Voltage Range		•	0		44	V		
CMRR	Common Mode Rejection Ratio (Note 5)		•	88 80	110 98		dB dB		
A _{VOL}	Large-Signal Voltage Gain	$ \begin{array}{l} V_S = 3V, V_0 = 500mV \ to \ 2.5V, \ R_L = 10k \\ V_S = 3V, \ 0^\circ C \leq T_A \leq 70^\circ C \\ V_S = 3V, \ -40^\circ C \leq T_A \leq 85^\circ C \end{array} $	•	150 100 75	400		V/mV V/mV V/mV		
		$ \begin{array}{l} V_S = 5V, V_0 = 500mV \ to \ 4.5V, \ R_L = 10k \\ V_S = 5V, \ 0^\circ C \leq T_A \leq 70^\circ C \\ V_S = 5V, \ -40^\circ C \leq T_A \leq 85^\circ C \end{array} $	•	300 200 150	800		V/mV V/mV V/mV		
V _{OL}	Output Voltage Swing LOW	No Load $I_{SINK} = 5mA$ $V_S = 5V$, $I_{SINK} = 10mA$	•		3 325 580	8 700 1300	mV mV mV		
V _{OH}	Output Voltage Swing HIGH	$V_{S} = 3V$, No Load $V_{S} = 3V$, I _{SOURCE} = 5mA	•	2.94 2.25	2.975 2.67		V V		
		$V_S = 5V$, No Load $V_S = 5V$, I _{SOURCE} = 10mA	•	4.94 3.80	4.975 4.45		V V		
I _{SC}	Short-Circuit Current (Note 2)	$V_S = 3V$, Short Output to Ground $V_S = 3V$, Short Output to V_{CC}		10 15	14 45		mA mA		
		$V_S = 5V$, Short Output to Ground $V_S = 5V$, Short Output to V_{CC}		15 15	22 60		mA mA		
PSRR	Power Supply Rejection Ratio	$V_{S} = 3V$ to 12.5V, $V_{CM} = V_{0} = 1V$	•	90	98		dB		
	Minimum Supply Voltage		•			2.7	V		
	Reverse Supply Voltage	$I_S = -100 \mu A$	•	25	40		V		
ls	Supply Current (Note 6)		•		190	250 295	μA μA		
	Supply Current, SHDN	V _{PIN5} = 2V, No Load (Note 6)	•		3	12	μA		
I _{SHDN}	Shutdown Pin Current	$ \begin{array}{l} V_{PIN5} = 0.3V, \mbox{ No Load (Note 6)} \\ V_{PIN5} = 2V, \mbox{ No Load (Note 5)} \\ V_{PIN5} = 3.3V \\ V_{PIN5} = 5V \end{array} $	•		0.2 1.0 2.5 4.3	15 5	nA μΑ μΑ		
	Output Leakage Current, SHDN	V _{PIN5} = 2V, No Load (Note 6)	•		0.02	1	μA		



3V AND 5V ELECTRICAL CHARACTERISTICS

The \bullet denotes the specifications which apply over the full operating temperature range of $-40^{\circ}C \le T_A \le 85^{\circ}C$, otherwise specifications are at $T_A = 25^{\circ}C$. $V_S = 3V$, 0V; $V_S = 5V$, 0V; $V_{SHDN} = V^-$, $V_{CM} = V_{OUT} =$ half supply unless otherwise specified. (Note 4)

		LT1					
SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
	Maximum Shutdown Pin Current	V _{PIN5} = 32V, No Load (Note 5)	•		20	150	μA
t _{ON}	Turn-On Time	$V_{PIN5} = 5V$ to 0V, $R_L = 10k$			45		μs
t _{OFF}	Turn-Off Time	$V_{PIN5} = 0V$ to 5V, $R_L = 10k$			3		μs
t _{SETTLING}	Settling Time	$0.1\% A_V = 1, \Delta V_0 = 2V$			9		μs
GBW	Gain-Bandwidth Product (Note 5)		•	650 550 500	1000		kHz kHz kHz
SR	Slew Rate (Note 7)	$\begin{array}{l} A_V = -1, \ R_L = \infty \\ 0^\circ C \leq T_A \leq 70^\circ C \\ -40^\circ C \leq T_A \leq 85^\circ C \end{array}$	•	0.210 0.185 0.170	0.35		V/µs V/µs V/µs

$\pm 15V$ ELECTRICAL CHARACTERISTICS

The \bullet denotes the specifications which apply over the full operating temperature range of $-40^{\circ}C \le T_A \le 85^{\circ}C$, otherwise specifications are at $T_A = 25^{\circ}C$. $V_S = \pm 15V$, $V_{CM} = 0V$, $V_{OUT} = 0V$, $V_{SHDN} = V^-$ unless otherwise specified. (Note 4)

				ា	1637C/LT16	6 3 71	
SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
V _{OS}	Input Offset Voltage		•		100	450 650 800	μV μV μV
		$\label{eq:mss} \begin{array}{l} \mbox{MS8 Package} \\ 0^\circ \mbox{C} \leq \mbox{T}_A \leq 70^\circ \mbox{C} \\ -40^\circ \mbox{C} \leq \mbox{T}_A \leq 85^\circ \mbox{C} \end{array}$	•		100	450 800 1150	μV μV μV
		$ \begin{array}{l} DD \mbox{ Package} \\ 0^\circ C \leq T_A \leq 70^\circ C \\ -40^\circ C \leq T_A \leq 85^\circ C \end{array} \end{array} $	•		125	650 1000 1150	μV μV μV
	Input Offset Voltage Drift (Note 9)	N8, S8 Packages, $-40^{\circ}C \le T_A \le 85^{\circ}C$ MS8 Package, $-40^{\circ}C \le T_A \le 85^{\circ}C$ DD Package, $-40^{\circ}C \le T_A \le 85^{\circ}C$	•		1 2 2	3 6 6	μV/°C μV/°C μV/°C
I _{OS}	Input Offset Current		•		1	6	nA
IB	Input Bias Current		•		17	50	nA
	Input Noise Voltage	0.1Hz to 10Hz			0.6		μV _{P-P}
e _n	Input Noise Voltage Density	f = 1kHz			27		nV/√Hz
i _n	Input Noise Current Density	f = 1kHz			0.08		pA/√Hz
R _{IN}	Input Resistance	Differential Common Mode, V _{CM} = –15V to 14V		1	3 2200		MΩ MΩ
CIN	Input Capacitance				4		pF
	Input Voltage Range		•	-15		29	V
CMRR	Common Mode Rejection Ratio	$V_{CM} = -15V$ to 29V	•	80	110		dB
A _{VOL}	Large-Signal Voltage Gain	$ \begin{array}{l} V_0 = \pm 14V, \ R_L = 10k \\ 0^\circ C \leq T_A \leq 70^\circ C \\ -40^\circ C \leq T_A \leq 85^\circ C \end{array} $	•	100 75 50	400		V/mV V/mV V/mV
V _{OL}	Output Voltage Swing LOW	No Load I _{SINK} = 5mA I _{SINK} = 10mA	•		-14.997 -14.680 -14.420	-14.25	V V V
							1637fd



$\pm 15V$ ELECTRICAL CHARACTERISTICS

The \bullet denotes the specifications which apply over the full operating temperature range of $-40^{\circ}C \le T_A \le 85^{\circ}C$, otherwise specifications are at $T_A = 25^{\circ}C$. $V_S = \pm 15V$, $V_{CM} = 0V$, $V_{OUT} = 0V$, $V_{SHDN} = V^-$ unless otherwise specified. (Note 4)

			LT1637C/LT1637I		637I		
SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
V _{OH}	Output Voltage Swing HIGH	No Load I _{SOURCE} = 5mA I _{SOURCE} = 10mA	•	14.9 14.2 13.7	14.967 14.667 14.440		V V V
I _{SC}	Short-Circuit Current (Note 2)	Short Output to GND $0^{\circ}C \le T_A \le 70^{\circ}C$ $-40^{\circ}C \le T_A \le 85^{\circ}C$	•	±25 ±20 ±15	±31.7		mA mA mA
PSRR	Power Supply Rejection Ratio	$V_{S} = \pm 1.5 V$ to $\pm 22 V$		90	115		dB
	Minimum Supply Voltage		•			±1.35	V
I _S	Supply Current		•		230	300 370	μΑ μΑ
	Positive Supply Current, SHDN	$V_{PIN5} = -20V$, $V_S = \pm 22V$, No Load			6	40	μA
I _{SHDN}	Shutdown Pin Current	V_{PIN5} = $-21.7V,V_S$ = $\pm22V,$ No Load V_{PIN5} = $-20V,V_S$ = $\pm22V,$ No Load	•		0.3 0.9	15 8	nA μA
	Maximum Shutdown Pin Current	$V_{PIN5} = 32V, V_{S} = \pm 22V$	•		20	150	μA
	Output Leakage Current, SHDN	$V_{PIN5} = -20V, V_S = \pm 22V, No Load$	•		0.02	2	μA
VL	Shutdown Pin Input Low Voltage	$V_{S} = \pm 22V$	•	-21.7	-21.6		V
V _H	Shutdown Pin Input High Voltage	$V_{S} = \pm 22V$	•		-20.8	-20.0	V
t _{ON}	Turn-On Time	$V_{PIN5} = -10V \text{ to } -15V, R_L = 10k$			35		μs
t _{OFF}	Turn-Off Time	$V_{PIN5} = -15V \text{ to } -10V, R_L = 10k$			3		μs
GBW	Gain-Bandwidth Product		•	750 650 600	1100		kHz kHz kHz
SR	Slew Rate	$ \begin{array}{l} A_V=-1,\ R_L=\infty,\ V_0=\pm 10V,\ Measure\ at\ V_0=\pm 5V\\ 0^\circ C\leq T_A\leq 70^\circ C\\ -40^\circ C\leq T_A\leq 85^\circ C \end{array} $	•	0.225 0.200 0.180	0.4		V/µs V/µs V/µs



3V AND 5V ELECTRICAL CHARACTERISTICS

The \bullet denotes the specifications which apply over the full operating temperature range of $-40^{\circ}C \le T_A \le 125^{\circ}C$ for LT1637H and $-55^{\circ}C \le T_A \le 125^{\circ}C$ for LT1637MP. $V_S = 3V$, 0V; $V_S = 5V$, 0V; $V_{CM} = V_{OUT} =$ half supply unless otherwise specified. (Note 4)

				LT16	637H/LT163		
SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
V _{OS}	Input Offset Voltage	out Offset Voltage			100	450	μV
			•			3	mV
	Input Offset Voltage Drift (Note 9)		•		3	10	μV/°C
l _{OS}	Input Offset Current		•			15	nA
		V _{CM} = 44V (Note 5)	•			10	μΑ
IB	Input Bias Current		•			150	nA
		$V_{CM} = 44V$ (Note 5)	•			100	μΑ
	Input Voltage Range		•	0.3		44	V
CMRR	Common Mode Rejection Ratio	$V_{CM} = 0.3V$ to $(V_{CC} - 1V)$ $V_{CM} = 0.3V$ to 44V	•	72 74			dB dB
	(Note 5)	••••	•		400		-
A _{VOL}	Large-Signal Voltage Gain	$V_{S} = 3V, V_{0} = 500mV$ to 2.5V, $R_{L} = 10k$		150 20	400		V/mV V/mV
		$V_{S} = 5V, V_{O} = 500 \text{mV} \text{ to } 4.5V, R_{I} = 10 \text{k}$		300	800		V/mV
		15 - 57, 70 - 555117 15 4.57, 11 - 151	•	35	000		V/mV
V _{OL}	Output Voltage Swing LOW	No Load	•			15	mV
02		I _{SINK} = 5mA	•			900	mV
		$V_{\rm S}$ = 5V, I _{SINK} = 10mA	•			1500	mV
V _{OH}	Output Voltage Swing HIGH	$V_{\rm S} = 3V$, No Load	•	2.90			V
		$V_{S} = 3V, I_{SOURCE} = 5mA$	•	2.05			V
		V _S = 5V, No Load V _S = 5V, I _{SOURCE} = 10mA		4.90 3.50			V V
PSRR	Power Supply Rejection Ratio	$V_{S} = 3V$, $V_{SOURCE} = 1000$ $V_{S} = 3V$ to 12.5V, $V_{CM} = V_{0} = 1V$		80			
ronn		$v_{\rm S} = 3v \ 10 \ 12.3v, \ v_{\rm CM} = v_0 = 1v$	•	2.7			dB V
	Minimum Supply Voltage		•				
	Reverse Supply Voltage	I _S = -100μA	•	23			V
I _S	Supply Current	(Note 6)			190	250 400	μΑ μΑ
	Supply Current, SHDN	V _{PIN5} = 2V, No Load (Note 6)				15	μΑ
	Shutdown Pin Current	$V_{PIN5} = 2.3$, No Load (Note 6) $V_{PIN5} = 0.3$ V, No Load (Note 6)				200	nA
I _{SHDN}		$V_{PIN5} = 0.37$, No Load (Note 5) $V_{PIN5} = 2V$, No Load (Note 5)				200	μΑ
	Output Leakage Current, SHDN	$V_{\text{PIN5}} = 2V$, No Load (Note 6)				5	μΑ
	Maximum Shutdown Pin Current	$V_{PIN5} = 32V$, No Load (Note 5)				200	μΑ
GBW	Gain-Bandwidth Product	f = 10 kHz (Note 5)		650	1000	200	kHz
GDW			•	350	1000		kHz
SR	Slew Rate	$A_{V} = -1, R_{I} = \infty$ (Note 7)		0.210	0.35		V/µs
		v ·,·· <u>L</u> (······)	•	0.1			V/µs



±15V ELECTRICAL CHARACTERISTICS

The \bullet denotes the specifications which apply over the full operating temperature range of $-40^{\circ}C \le T_A \le 125^{\circ}C$ for LT1637H and $-55^{\circ}C \le T_A \le 125^{\circ}C$ for LT1637MP. V_S = ±15V, V_{CM} = 0V, V_{OUT} = 0V, V_{SHDN} = V⁻, unless otherwise specified. (Note 4)

				LT16	37H/LT16	37MP	
SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
V _{OS}	Input Offset Voltage				100	550	μV
			•			3.4	mV
	Input Offset Voltage Drift (Note 9)		•		3	11	μV/°C
l _{OS}	Input Offset Current		•			25	nA
I _B	Input Bias Current		•			250	nA
CMRR	Common Mode Rejection Ratio	V _{CM} = -14.7V to 29V	•	72			dB
A _{VOL}	Large-Signal Voltage Gain	$V_0 = \pm 14V, R_L = 10k$		100	400		V/mV
			•	4			V/mV
V ₀	Output Voltage Swing	No Load	•			±14.8	V
		$I_{OUT} = \pm 5 \text{mA}$	•			±14.0	V V
	Deven Oversky Deisetien Detie	$I_{OUT} = \pm 10$ mA	•	0.4		±13.4	
PSRR	Power Supply Rejection Ratio	$V_{\rm S} = \pm 1.5 V \text{ to } 22 V$	•	84			dB
	Minimum Supply Voltage		•	±1.35			V
I _S	Supply Current				230	300	μA
			•			500	μA
	Positive Supply Current, SHDN	$V_{PIN5} = -20V, V_S = \pm 22V, No Load$	•			60	μA
I _{SHDN}	Shutdown Pin Current	$V_{PIN5} = -21.7V, V_S = \pm 22V, No Load$	•			200	nA
		$V_{PIN5} = -20V, V_S = \pm 22V, No Load$	•			10	μA
	Maximum Shutdown Pin Current	$V_{PIN5} = 32V, V_S = \pm 22V$	•			200	μA
	Output Leakage Current, SHDN	$V_{PIN5} = -20V, V_S = \pm 22V, No Load$	•			100	μΑ
VL	Shutdown Pin Input Low Voltage	$V_{S} = \pm 22V$	•			-21.7	V
V _H	Shutdown Pin Input High Voltage	$V_{S} = \pm 22V$	•	-20			V
GBW	Gain-Bandwidth Product	f = 10kHz		750	1100		kHz
			•	400			kHz
SR	Slew Rate	$A_V = -1, R_L = \infty, V_0 = \pm 10V,$		0.225	0.4		V/µs
		Measure at $V_0 = \pm 5V$		0.1			V/µs

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: A heat sink may be required to keep the junction temperature below absolute maximum. The θ_{JA} specified for the DD package is with minimal PCB heat spreading metal. Using expanded metal area on all layers of a board reduces this value.

Note 3: The LT1637C and LT1637I are guaranteed functional over the operating temperature range of -40° C to 85° C. The LT1637H is guaranteed functional over the operating temperature range of -40° C to 125° C. The LT1637MP is guaranteed functional over the operating temperature range -55° C to 125° C.

Note 4: The LT1637C is guaranteed to meet specified performance from 0°C to 70°C. The LT1637C is designed, characterized and expected to meet

specified performance from -40° C to 85° C but is not tested or QA sampled at these temperatures. The LT1637I is guaranteed to meet specified performance from -40° C to 85° C. The LT1637H is guaranteed to meet specified performance from -40° C to 125° C and the LT1637MP is guaranteed to meet specified performance from -55° C to 125° C.

Note 5: V_S = 5V limits are guaranteed by correlation to V_S = 3V and V_S = $\pm 15V$ or V_S = $\pm 22V$ tests.

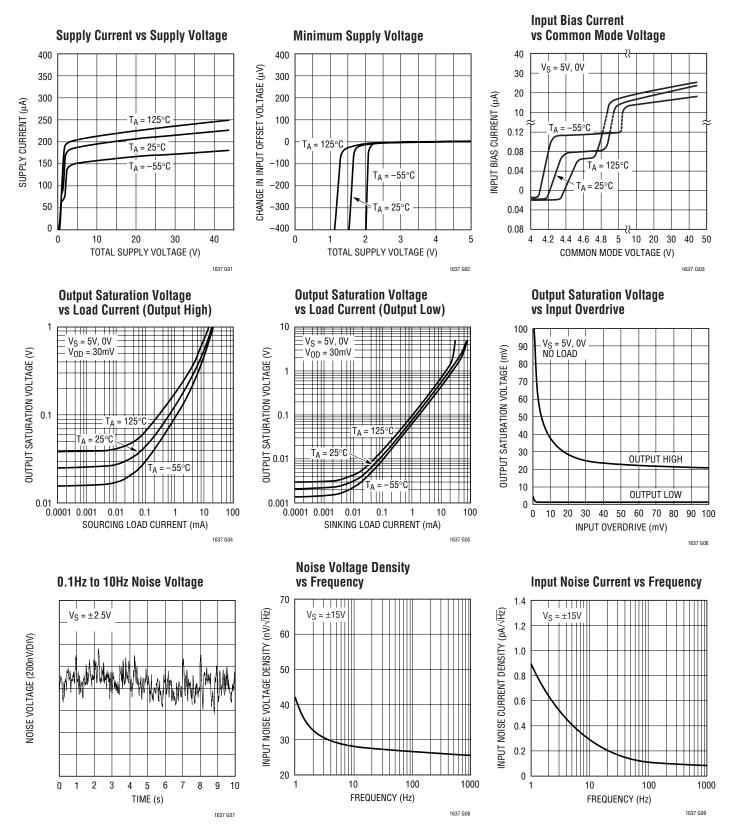
Note 6: V_S = 3V limits are guaranteed by correlation to V_S = 5V and V_S = $\pm 15V$ or V_S = $\pm 22V$ tests.

Note 7: Guaranteed by correlation to slew rate at V_S = $\pm 15V$ and GBW at V_S = 3V and V_S = $\pm 15V$ tests.

Note 8: This specification implies a typical input offset voltage of 650μ V at V_{CM} = 44V and a maximum input offset voltage of 5.4mV at V_{CM} = 44V. **Note 9:** This parameter is not 100% tested.

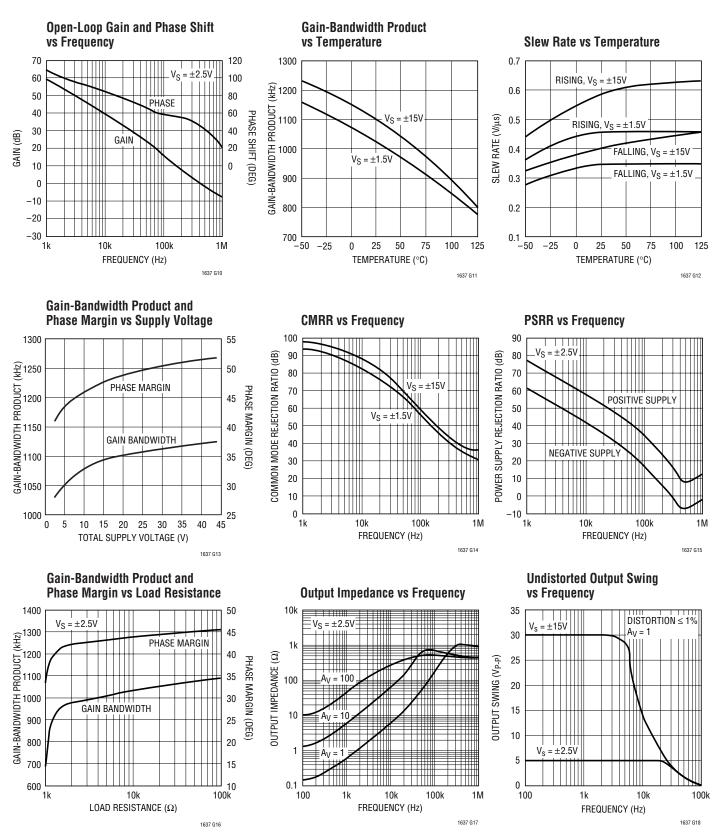


TYPICAL PERFORMANCE CHARACTERISTICS





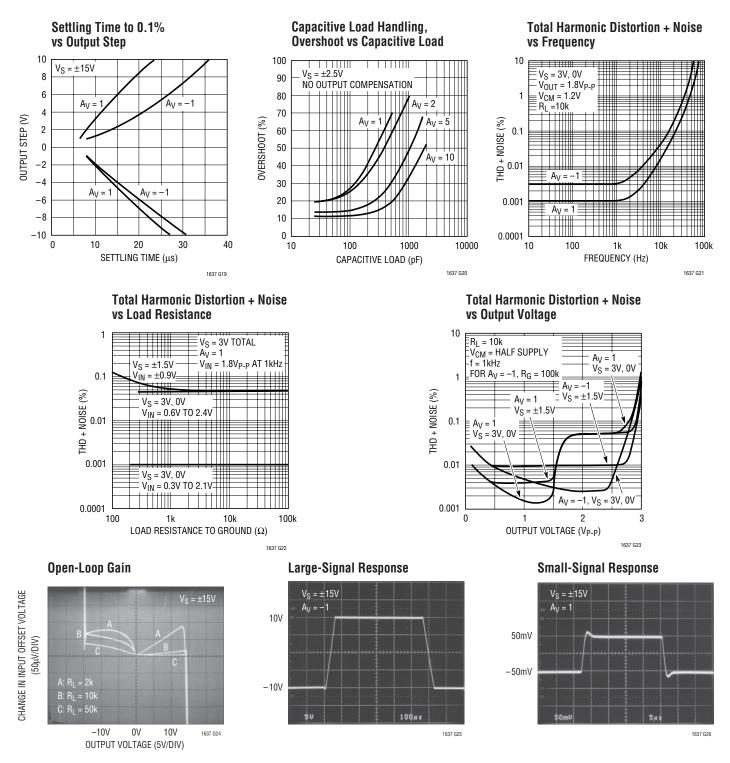
TYPICAL PERFORMANCE CHARACTERISTICS







TYPICAL PERFORMANCE CHARACTERISTICS





APPLICATIONS INFORMATION

Supply Voltage

The positive supply pin of the LT1637 should be bypassed with a small capacitor (about 0.01μ F) within an inch of the pin. When driving heavy loads an additional 4.7μ F electrolytic capacitor should be used. When using split supplies, the same is true for the negative supply pin.

The LT1637 is protected against reverse battery voltages up to 25V. In the event a reverse battery condition occurs, the supply current is typically less than 1nA.

When operating the LT1637 on total supplies of 30V or more, the supply must not be brought up faster than 1 μ s. This is especially true if low ESR bypass capacitors are used. A series RLC circuit is formed from the supply lead inductance and the bypass capacitor. 5 Ω of resistance in the supply or the bypass capacitor will dampen the tuned circuit enough to limit the rise time.

Inputs

The LT1637 has two input stages, NPN and PNP (see the Simplified Schematic), resulting in three distinct operating regions as shown in the Input Bias Current vs Common Mode typical performance curve.

For input voltages about 0.9V or more below V⁺, the PNP input stage is active and the input bias current is typically -20nA. When the input voltage is about 0.5V or less from V⁺, the NPN input stage is operating and the input bias current is typically 80nA. Increases in temperature will cause the voltage at which operation switches from the PNP stage to the NPN stage to move towards V⁺. The input offset voltage of the NPN stage is untrimmed and is typically 600 μ V.

A Schottky diode in the collector of each NPN transistor of the NPN input stage allows the LT1637 to operate with either or both of its inputs above V⁺. At about 0.3V above V⁺ the NPN input transistor is fully saturated and the input bias current is typically 23 μ A at room temperature. The input offset voltage is typically 600 μ V when operating above V⁺. The LT1637 will operate with its input 44V above V⁻ regardless of V⁺. The inputs are protected against excursions as much as 22V below V⁻ by an internal 1.3k resistor in series with each input and a diode from the input to the negative supply. There is no output phase reversal for inputs up to 5V below V⁻. There are no clamping diodes between the inputs and the maximum differential input voltage is 44V.

Output

The output voltage swing of the LT1637 is affected by input overdrive as shown in the typical performance curves. When monitoring input voltages within 100mV of V⁺, gain should be taken to keep the output from clipping.

The output of the LT1637 can be pulled up to 25V beyond V⁺ with less than 1nA of leakage current, provided that V⁺ is less than 0.5V.

The normally reverse biased substrate diode from the output to V^- will cause unlimited currents to flow when the output is forced below V^- . If the current is transient and limited to 100mA, no damage will occur.

The LT1637 is internally compensated to drive at least 200pF of capacitance under any output loading conditions. A 0.22μ F capacitor in series with a 150Ω resistor between the output and ground will compensate these amplifiers for larger capacitive loads, up to 4700pF, at all output currents.

Distortion

There are two main contributors of distortion in op amps: output crossover distortion as the output transitions from sourcing to sinking current and distortion caused by nonlinear common mode rejection. Of course, if the op amp is operating inverting there is no common mode induced distortion. When the LT1637 switches between input stages there is significant nonlinearity in the CMRR. Lower load resistance increases the output crossover distortion, but has no effect on the input stage transition distortion. For lowest distortion the LT1637 should be operated single supply, with the output always sourcing current and with the input voltage swing between ground and (V⁺ – 0.9V). See the Typical Performance Characteristics curves.



APPLICATIONS INFORMATION

Gain

The open-loop gain is less sensitive to load resistance when the output is sourcing current. This optimizes performance in single supply applications where the load is returned to ground. The typical performance photo of Open-Loop Gain for various loads shows the details.

Shutdown

The LT1637 can be shut down two ways: using the shutdown pin or bringing V⁺ to within 0.5V of V⁻. When V⁺ is brought to within 0.5V of V⁻ both the supply current and output leakage current drop to less than 10nA. When the shutdown pin is brought 1.2V above V⁻, the supply current drops to about 3μ A and the output leakage current is less than 1μ A, independent of V⁺. In either case the input bias current is less than 0.1nA (even if the inputs are 44V above the negative supply).

The shutdown pin can be taken up to 32V above V⁻. The shutdown pin can be driven below V⁻, however the pin current through the substrate diode should be limited with an external resistor to less than 10mA.

Input Offset Nulling

The input offset voltage can be nulled by placing a 10k potentiometer between Pins 1 and 8 with its wiper to V⁻ (see Figure 1). The null range will be at least \pm 3mV.

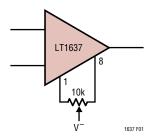
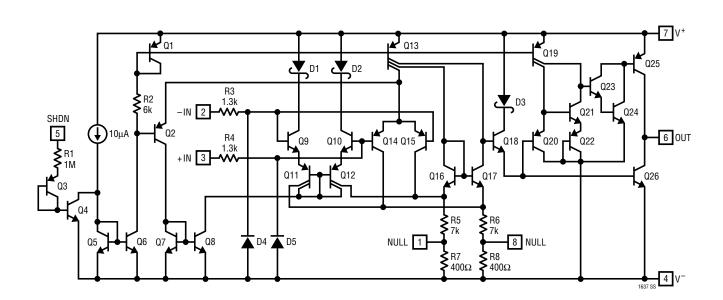


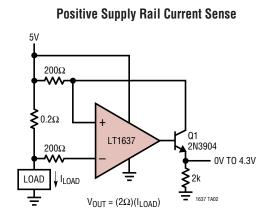
Figure 1. Input Offset Nulling



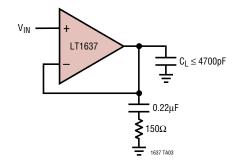
SIMPLIFIED SCHEMATIC



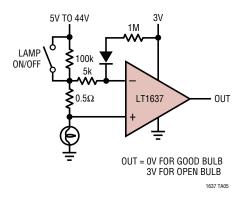
TYPICAL APPLICATIONS



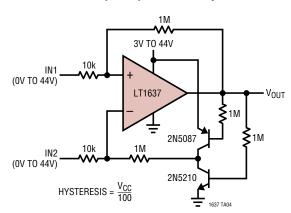
Optional Output Compensation for Capacitive Loads Greater Than 200pF



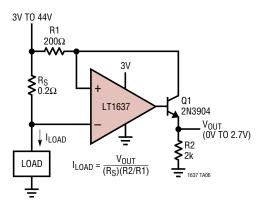
Lamp Outage Detector



Over-The-Top Comparator with Hysteresis

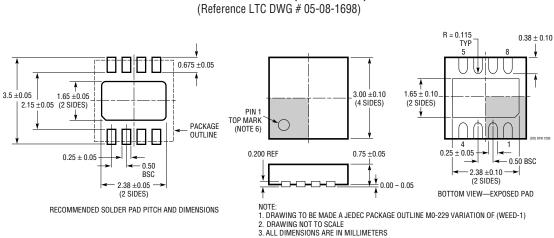


Over-The-Top Current Sense





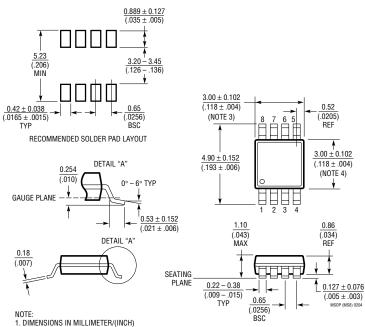
PACKAGE DESCRIPTION



DD Package 8-Lead Plastic DFN ($3mm \times 3mm$)

ALL DIMENSIONS ARE IN MILLIMETERS
DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.15mm ON ANY SIDE
EXPOSED PAD SHALL BE SOLDER PLATED
SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION ON TOP AND BOTTOM OF PACKAGE

MS8 Package 8-Lead Plastic MSOP (Reference LTC DWG # 05-08-1660)



- 1. DIMENSIONS IN WILLIME LEVELYINCH) 2. DRAWING NOT TO SCALE 3. DIMENSION DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.152mm (.006') PER SIDE 4. DIMENSION DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS. INTERLEAD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.152mm (.006') PER SIDE
- 5. LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.102mm (.004") MAX



PACKAGE DESCRIPTION

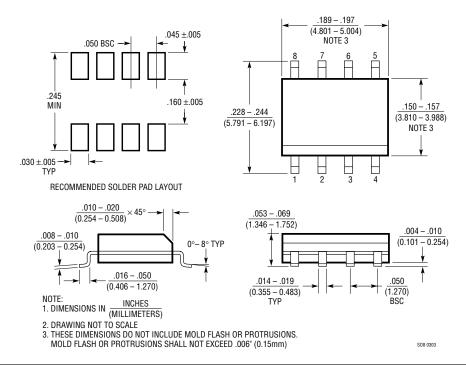
8-Lead PDIP (Narrow .300 Inch) (Reference LTC DWG # 05-08-1510) .400* (10.160) MAX 5 8 7 6 .255 ± .015* (6.477 ± 0.381) 2 3 4 1 $.130 \pm .005$.300 – .325 .045 – .065 (7.620 - 8.255) $(\overline{1.143 - 1.651})$ $(\overline{3.302 \pm 0.127})$.065 (1.651) .008 – .015 TYP .120 $(\overline{0.203 - 0.381})$.020 (3.048) .325 ^{+.035} -.015 MIN (0.508) <u>.100</u> (2.54) MIN .018 ± .003 8.255^{+0.889} -0.381 (0.457 ± 0.076) N8 1002 BSC NOTE: INCHES

N8 Package

1. DIMENSIONS ARE <u>INCHES</u> *THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.

MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED .010 INCH (0.254mm)

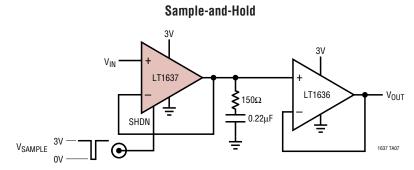
S8 Package 8-Lead Plastic Small Outline (Narrow .150 Inch) (Reference LTC DWG # 05-08-1610)





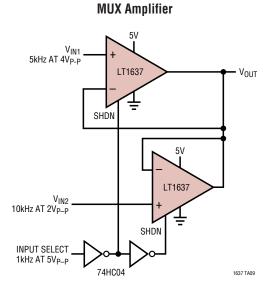
Information furnished by Linear Technology Corporation is believed to be accurate and reliable. However, no responsibility is assumed for its use. Linear Technology Corporation makes no representation that the interconnection of its circuits as described herein will not infringe on existing patent rights.

TYPICAL APPLICATIONS

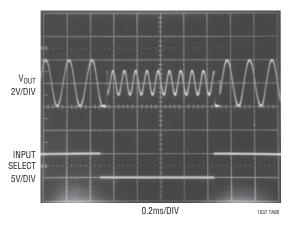


DROOP (LT1636 BUFFER): 200mV/s DROOP INTO HIGH IMPEDANCE : LESS THAN 0.625mV/s





MUX Amplifier Waveforms



RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LT1078/LT1079 LT2078/LT2079	Dual/Quad 55µA Max, Single Supply, Precision Op Amps	Input/Output Common Mode Includes Ground, 70 μ V V _{OS(MAX)} and 2.5 μ V/°C Drift (Max), 200kHz GBW, 0.07V/ μ s Slew Rate
LT1178/LT1179 LT2178/LT2179	Dual/Quad 17µA Max, Single Supply, Precision Op Amps	Input/Output Common Mode Includes Ground, 70 μ V V _{OS(MAX)} and 4 μ V/°C Drift (Max), 85kHz GBW, 0.04V/ μ s Slew Rate
LT1366/LT1367	Dual/Quad Precision, Rail-to-Rail Input and Output Op Amps	475µV V _{OS(MAX)} , 500V/mV A _{VOL(MIN)} , 400kHz GBW
LT1490/LT1491	Dual/Quad Over-The-Top Micropower, Rail-to-Rail Input and Output Op Amps	Single Supply Input Range: –0.4V to 44V, Micropower 50µA per Amplifier, Rail-to-Rail Input and Output, 200kHz GBW
LT1636	Single Over-The-Top Micropower Rail-to-Rail Input and Output Op Amp	55 μ A Supply Current, V _{CM} Extends 44V above V _{EE} , Independent of V _{CC} ; MSOP Package, Shutdown Function
LT1638/LT1639	Dual/Quad 1.2MHz Over-The-Top Micropower, Rail-to-Rail Input and Output Op Amps	0.4V/µs Slew Rate, 230µA Supply Current per Amplifier
LT1782	Micropower, Over-The-Top, SOT-23, Rail-to-Rail Input and Output Op Amp	SOT-23, 800μV V _{OS(MAX)} , I _S = 55μA (Max), Gain-Bandwidth = 200kHz, Shutdown Pin
LT1783	1.2MHz, Over-The-Top, Micropower, Rail-to-Rail Input and Output Op Amp	SOT-23, 800 μ V V _{OS(MAX)} , I _S = 300 μ A (Max), Gain-Bandwidth = 1.2MHz, Shutdown Pin

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